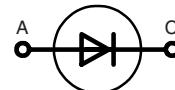


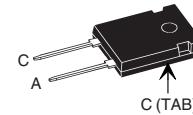
HiPerFRED™ Epitaxial Diode with soft recovery

I_{FAV} = 30 A
V_{RRM} = 600 V
t_{rr} = 30/35 ns

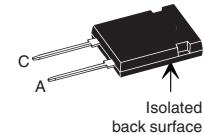
| V _{RSM} V | V _{RRM} V | Type |
|-----------------------|-----------------------|--------------|
| 600 | 600 | DSEP 30-06A |
| 600 | 600 | DSEP 30-06B |
| 600 | 600 | DSEP 30-06BR |



TO-247 AD
Version A



ISOPLUS 247™
Version BR



A = Anode, C = Cathode

| Symbol | Conditions | Maximum Ratings | | Features |
|----------------------|---|-----------------|----|----------|
| I _{FRMS} | | 70 | A | |
| I _{FAVM} | rect., d = 0.5; T _C (Vers. A) = 135°C T _C (Vers. B) = 125°C; T _C (Vers. BR) = 115°C | 30 | A | |
| I _{FSM} | T _{VJ} = 45°C; t _p = 10 ms (50 Hz), sine | 250 | A | |
| E _{AS} | T _{VJ} = 25°C; non-repetitive I _{AS} = 1.3 A; L = 180 µH | 0.2 | mJ | |
| I _{AR} | V _A = 1.5·V _R typ.; f = 10 kHz; repetitive | 0.1 | A | |
| T _{VJ} | | -55...+175 | °C | |
| T _{VJM} | | 175 | °C | |
| T _{stg} | | -55...+150 | °C | |
| P _{tot} | T _C = 25°C (Vers. BR) | 165 | W | |
| | | 135 | W | |
| M _d * | mounting torque | 0.8...1.2 | Nm | |
| F _c | mounting force with clip | 20...120 | N | |
| V _{ISOL} ** | 50/60 Hz, RMS, t = 1 minute, leads-to-tab | 2500 | V~ | |
| Weight | typical | 6 | g | |

* Version A only; ** Version BR only

| Symbol | Conditions | Characteristic max. Values | | |
|----------------------|---|----------------------------|--------------|----------|
| | | Vers. A | Vers. B | |
| I _R ① | T _{VJ} = 25°C V _R = V _{RRM} T _{VJ} = 150°C V _R = V _{RRM} | 250 1 | 250 2 | µA mA |
| V _F ② | I _F = 30 A; T _{VJ} = 150°C T _{VJ} = 25°C | 1.25 1.60 | 1.56 2.51 | V V |
| R _{thJC} | | 0.9 | 0.9 | K/W |
| R _{thJC} | Version BR | | 1.1 | K/W |
| R _{thCH} | typ. | 0.25 | 0.25 | K/W |
| t _{rr} typ. | I _F = 1 A; -di/dt = 200 A/µs; V _R = 30 V; T _{VJ} = 25°C | 35 | 30 | ns |
| I _{RM} typ. | V _R = 100 V; I _F = 50 A; -di _F /dt = 100 A/µs T _{VJ} = 100°C | 6 | 4 | A |

Pulse test: ① Pulse Width = 5 ms, Duty Cycle < 2.0 %

② Pulse Width = 300 µs, Duty Cycle < 2.0 %

Data according to IEC 60747 and per diode unless otherwise specified.

IXYS reserves the right to change limits, test conditions and dimensions.

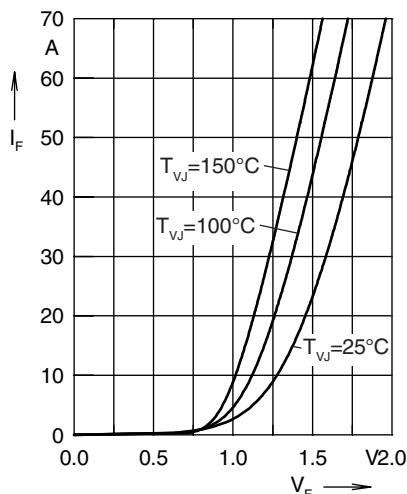


Fig. 1 Forward current I_F versus V_F

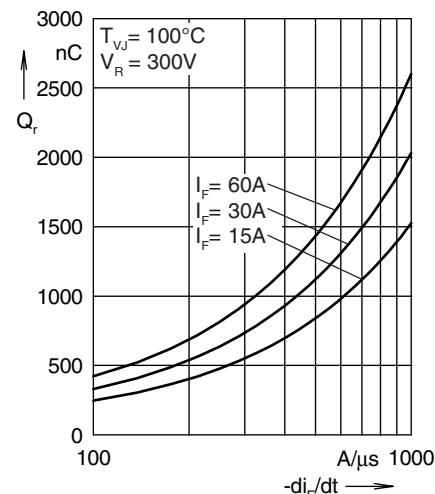


Fig. 2 Reverse recovery charge Q_r versus $-di_F/dt$

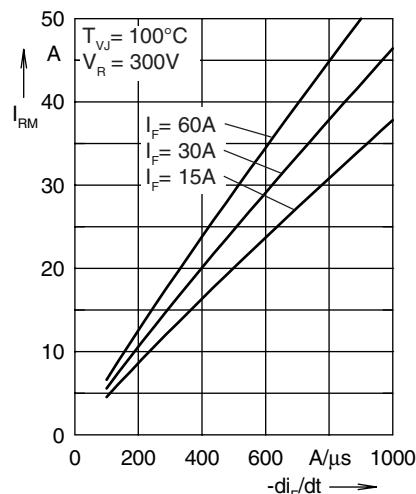


Fig. 3 Peak reverse current I_{RM} versus $-di_F/dt$

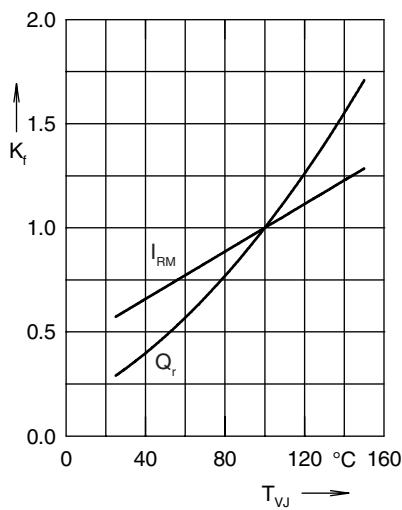


Fig. 4 Dynamic parameters Q_r , I_{RM} versus T_{VJ}

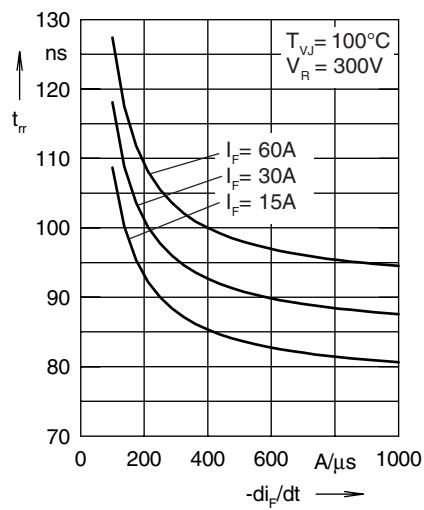


Fig. 5 Recovery time t_{rr} versus $-di_F/dt$

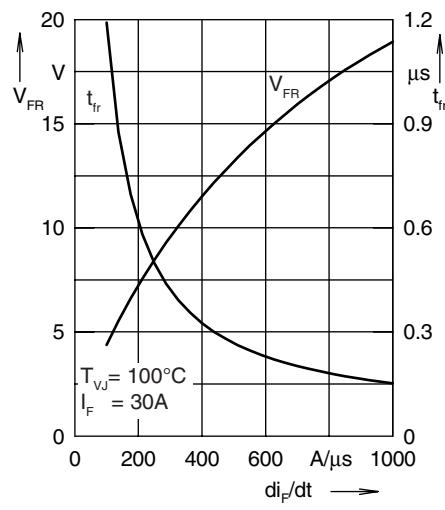


Fig. 6 Peak forward voltage V_{FR} and t_{tr} versus di_F/dt

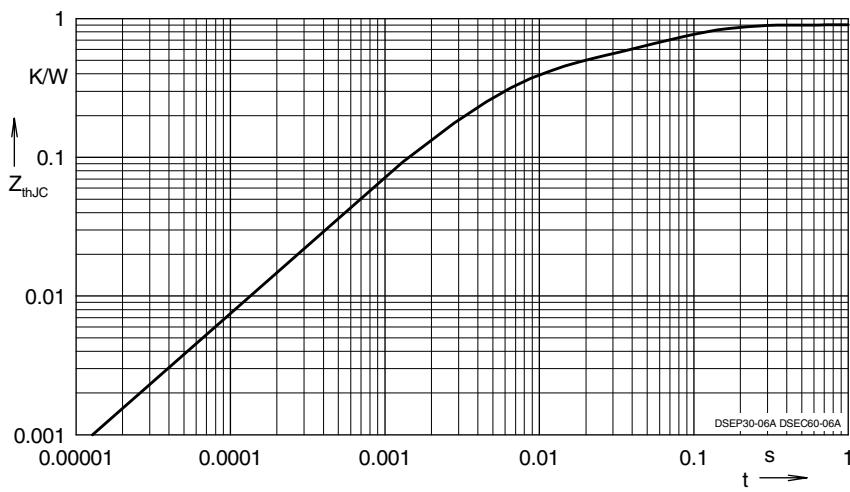


Fig. 7 Transient thermal resistance junction to case

Constants for Z_{thJC} calculation:

| i | R_{thi} (K/W) | t_i (s) |
|---|-----------------|-----------|
| 1 | 0.465 | 0.0052 |
| 2 | 0.179 | 0.0003 |
| 3 | 0.256 | 0.0396 |

NOTE: Fig. 2 to Fig. 6 shows typical values

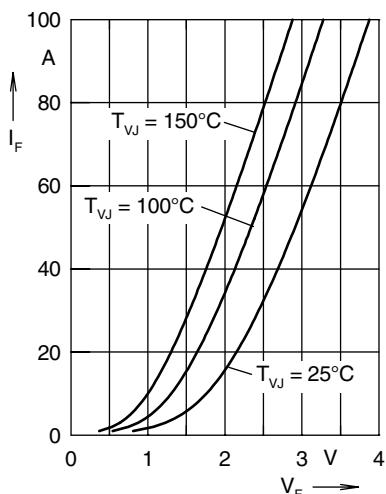


Fig. 1 Forward current I_F versus V_F

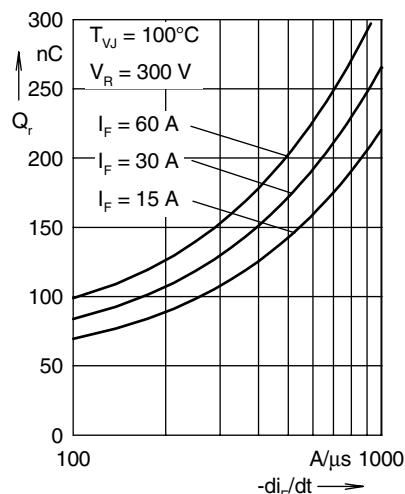


Fig. 2 Reverse recovery charge Q_r versus $-di_F/dt$

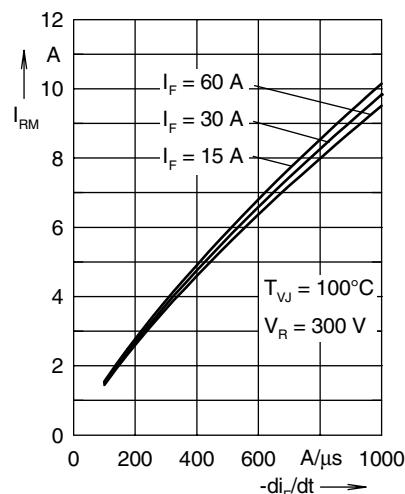


Fig. 3 Peak reverse current I_{RM} versus $-di_F/dt$

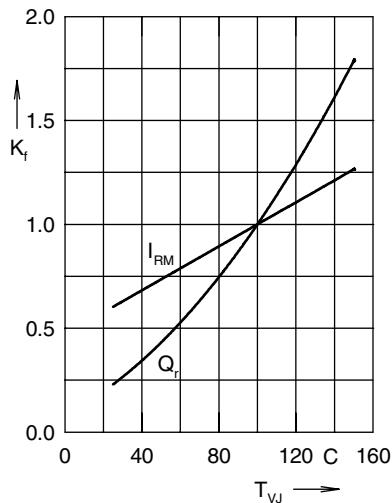


Fig. 4 Dynamic parameters Q_r , I_{RM} versus T_{VJ}

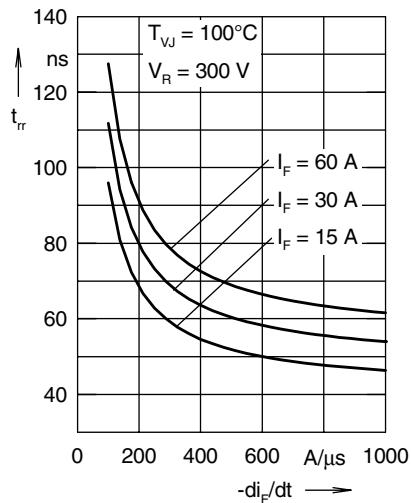


Fig. 5 Recovery time t_{rr} versus $-di_F/dt$

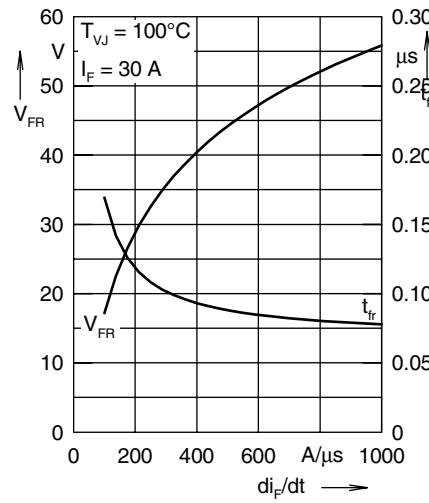


Fig. 6 Peak forward voltage V_{FR} and t_{rr} versus di_F/dt

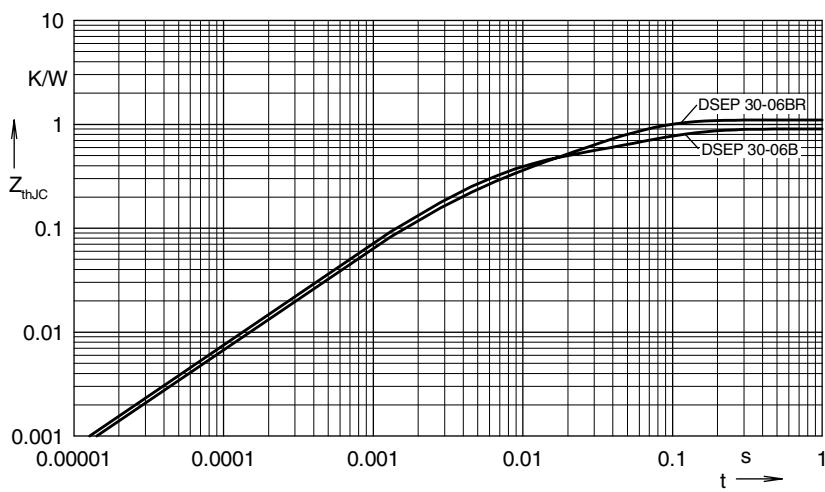


Fig. 7 Transient thermal resistance junction to case

Constants for Z_{thJC} calculation ..B:

| i | R_{thi} (K/W) | t_i (s) |
|---|-----------------|-----------|
| 1 | 0.465 | 0.0052 |
| 2 | 0.179 | 0.0003 |
| 3 | 0.256 | 0.0397 |

Constants for Z_{thJC} calculation ..BR:

| i | R_{thi} (K/W) | t_i (s) |
|---|-----------------|-----------|
| 1 | 0.368 | 0.0052 |
| 2 | 0.1417 | 0.0003 |
| 3 | 0.0295 | 0.0004 |
| 4 | 0.5604 | 0.0092 |

NOTE: Fig. 2 to Fig. 6 shows typical values